



# **Optical Emission Spectroscopy Sensors Endpoint Detection Solutions**





# Dry etching, cleaning or PECVD (Plasma Enhanced Chemical Vapor deposition) or atomic layer deposition/etch (ALD/ALE) process

Make your integrated circuits production faster, with constant quality by using HORIBA realtime in-situ advanced endpoint detection solutions.

Plasma is an important technology used in various process equipment such as dry etching, sputtering, plasma CVD, and plasma surface treatment in the semiconductor manufacturing process. These manufacturing equipment are used in a wide range of industrial fields, such as memory and logic semiconductors, compound semiconductors (LED, Laser, VCSEL), FPD / OLED or electronic components.

Plasma processes are composed of many deposition and etching steps made on various tools and chambers. All these operations can introduce variability and defects, creating lower device performance. To ensure and guarantee excellent reproducibility, accuracy, quality, yield, and throughput, it is critical to qualify and quantify such manufacturing processes.

- Real time, in-situ, wafer process monitoring
- Accurate chamber health and fault detection monitoring
- Wafer uniformity control
- Endpoint information for
  - Laver interfaces even for low open area structures
  - Dry chamber cleaning

HORIBA has developed a specific line of optical sensors, based on optical emission spectroscopy (OES), dedicated to endpoint detection and plasma chamber condition monitoring.

With endpoint technology, each step is controlled in real-time to stop at the exact required point, avoiding under/over etch/deposition. With health monitoring and fault detection follow up, process steps can be operated wafer after wafer, lot after lot, respecting standard POR (Process Of Reference) within chambers.

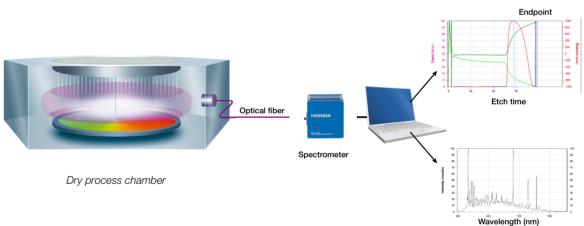
# Optical Emission Spectroscopy sensor and endpoint detection

HORIBA has developed different sensors for vacuum chambers to manage endpoint detection for dry etching process and PECVD or more complex process, such as atomic layer deposition or atomic layer etch (ALD/ALE).

Such sensors, based on Optical Emission Spectroscopy (OES), monitor the global plasma emission during the process. OES sensors monitor relative intensity changes in the plasma emission spectrum during etching or deposition process, as elements/ compounds from layers etched or deposited, react with the plasma.

By selecting appropriate wavelengths of the emission spectrum, monitoring intensity changes or stability over time, the endpoint of these etching or deposition process can be accurately determined.

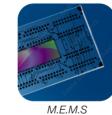
The endpoint detection consists of detecting slope changes (upward or downward) in the intensity of the relevant wavelengths to stop processes at layer interfaces. With accurate endpoint detection algorithms, etch processes can be stopped precisely when required improving wafer to wafer uniformity.



# HORIBA OES Sensors present unique benefits with:

- Powerful algorithms and signal treatments to allow endpoint detection even on low open area or cyclic signals. Reinforcing operational stability in the hostile environments of round-the-clock manufacturing lines.
- Dedicated "Turnkey" solutions including hardware and software tools to increase performance system throughput and predict if preventive maintenance is necessary.
- Smart software for complex processes. Based on innovative Al, unsupervised technologies and unique software architecture, including analytical methodology and sophisticated signal processing, these software solutions satisfies all the needs of insitu plasma process control: data classification, smart wavelength selection for easy detection algorithm.















Photovoltaic

LED and compounds



# Endpoint detection, chamber health monitoring, fault detection, chamber gas controls and cleaning

HORIBA OES sensors can be used to detect the etching endpoint at the interface of two layers or for monitoring chamber cleaning; Main applications are semiconductors, microelectronics (memory and logic circuits), optoelectronics (telecommunications, laser diodes, LEDs, VCSELs), displays, photovoltaics, hard disks, MEMS (Micro-Electro-Mechanical-Systems: micropumps, accelerometers, micromotors, gears), optical coatings, chamber cleaning, failure analysis, ....

# Endpoint detection

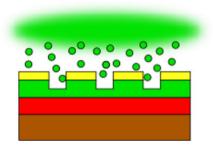
Non-exhaustive list of typical materials involved in etching steps that can be monitored for endpoint interface detection are:

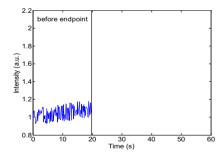
- Dielectrics (Si0,,TiO,, Ga,O,, As,O,, Si,N,, AIN, Ta,O,, SiON, etc.
- Si, SiC, photoresist, SOI, etc.
- Compounds III-V (InP, GaAs, AlGaAs, InGaN, AlGaN, GaN, etc.), II-VI (ZnO, CdTe, HgCdTe, etc.), IV-IV, etc.

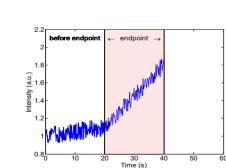
**During endpoint detection** 

• Metals: Ti, Cr, Al, W, etc.

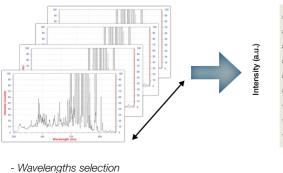
#### Before endpoint detection



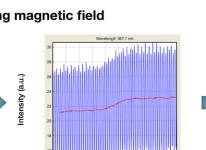




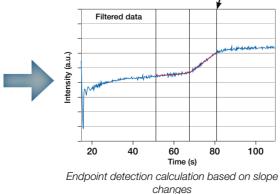
#### From raw data to endpoint with rotating magnetic field



- Single or multi wavelengths



Time (s) Signal processing



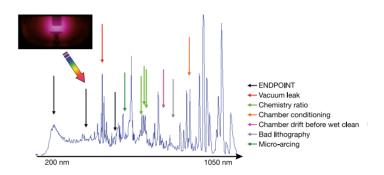
30 Time (s)

Endpoint

After endpoint detection

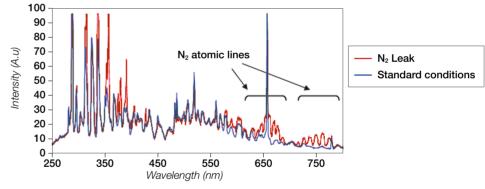
## Chamber health monitoring

Chamber health monitoring is the long term observation, between two wet cleans, to ensure that the chamber remains in an acceptable state for reproducible processing. This guarantees "standard chamber" conditions and alerts if conditions are abnormal (fault detection, drift) requiring preventive maintenance and thus allowing external checking/control to be reduced.



# Fault detection of chamber gas controls

OES sensors can detect faults, leaks, arcing or abnormal gas concentrations used for plasma generation... Alerts can be set automatically to inform users about non standard conditions.



Example of N<sub>2</sub> leak (red spectra) versus standard conditions (Nominal blue spectra)

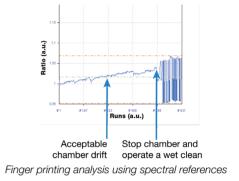
### Cleaning

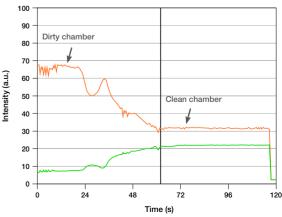
OES can also be used to follow chamber cleaning steps, material or impurities, wall deposition removal, and to keep chambers in good condition.

This helps to:

- Reduce tool to tool variability
- Optimize cleaning step duration .
- Save gas and energy costs •
- Improve tool throughput

Peak or area intensity...





Example of endpoint on cleaning

# Low open area: A challenge for endpoint detection

## Logic chip and contact etching: "low open area" processes, less than 2%

Logic circuit devices are characterized by the critical dimension of their gate electrode. This is minimized in order to increase their operating frequency. The complex wiring of logic-circuit chips, requires multiple levels of metallization, placing increased emphasis on «back-end-of-line» (BEOL) oxide and/or metal etching.

# The contact dry etch process (CA process) is a critical step in the fabrication of logic devices where the main risk is obtaining an open contact.

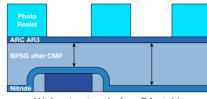
The four main challenges in contact etch process monitoring are:

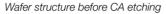
- Low open area of oxide, less than 2%
- Highly selective fluorine process
- Rotating magnetic field employed in the etch tool
- Two types of contacts (pad and floating gate) have to be etched during a single step

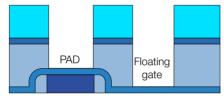
HORIBA OES sensors are designed to overcome the challenges presented by logic chip manufacturing and also to meet the plasma etching needs required for the next generation of such components.

Essa.	
	Floating gate
SEGU1 55002	

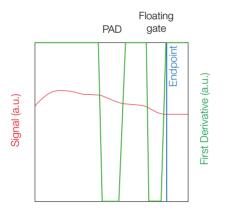
SEM cross section after the contact etch process







Wafer structure after CA etching



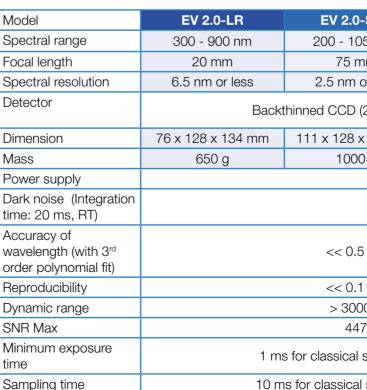
Example of endpoint detection display and signal treatment



# Different sensors for different applications

The OES sensors family, called EV 2.0, includes several versions with different resolution and spectral range, to cover different applications. Such sensors are mounted on the chamber viewport. They can work on single chamber or on cluster tools, and offer SMA fiber or direct coupling to the chamber.





#### For chamber cleaning control

Model: EV 2.0 LR Range: 300 - 900 nm Low resolution: 6.5 nm

### For Standard Endpoint

Model: EV 2.0 STD Range: 200 - 1050 nm Standard resolution: 2.5 nm

# For specific applications requiring high resolution to separate species

Model: EV 2.0 HR Range: 300 - 800 nm High resolution: 1-1.5 nm

# For Complex Endpoint: where any photon collection is key to catch process quality and Endpoint

Model: EV 2.0 HTR Range: 190 - 900 nm High Throughput & High resolution: 1 nm

	EV 2.0-STD	EV 2.0-HR	EV 2.0-HTR		
٦	200 - 1050 nm	300 - 800 nm	190 - 900 nm		
	75 mm	75 mm	99 mm		
S	2.5 nm or less	down to 1 nm	1 nm		
Backt	hinned CCD (2048 x 16 p	Backthinned CCD (2048 x 192 pixels)			
mm	111 x 128 x 134 mm	111 x 128 x 134 mm	147 x 176 x 134 mm		
	1000 g	800 g	2800 g		
DC 24V					
0.05% Full scale					
	<< 0.5 nm	<< 0.02 nm			
	<< 0.1 nm	<< 0.05 nm			
	> 3000/1	> 5200/1			
	447	500			
1 ms for classical sensor/ 0.1 ms for fast sensor (ALE/ALD)					
10 ms for classical sensor/ 1.4 ms for fast sensor (ALE/ALD)					

# Software platforms

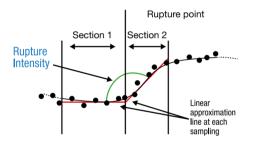
HORIBA has developed two software interfaces to follow real time processes to automatically create recipe:

- SIGMA\_P, for real time acquisitions and process follow up
- RECIPE DESIGNER 2.0, for automatic generation of endpoint recipes

# SIGMA\_P: A smart software platform for "Real Time"/"in-situ" endpoint production control and monitoring

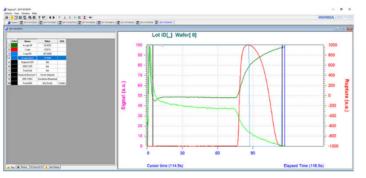
SIGMA\_P is a global software platform that allows you in real time to :

- Monitor the process
- Acquire spectra
- Load, modify and enhance endpoint recipes
- Reprocess data and check endpoint detection (EPD) validity
- Perform production controls

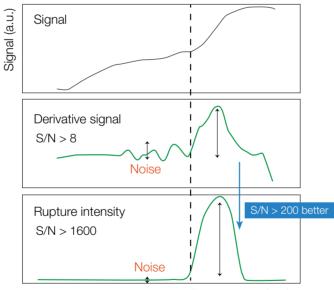


Powerful rupture algorithm calculation

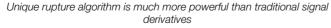
- Unique Rupture algorithm, more powerful than classical signal derivative
- Large panel of advanced algorithms for EPD processing
- One click concept for easy algorithm generation
- Expandable platform (single chamber or cluster tools)
- Fast recipe configuration for robust endpoint creation
- Advanced Equipment Controls (AEC) / Process Controls (APC) (wafer2wafer, Run2Run, Lot2Lot, Clean2Clean)
- SQL database for easy data comparison and interpretation
- Different users levels
- Reprocessing functions to validate a process
   (EPD)
- Statistical tools
- Flexible tool remote connectivity

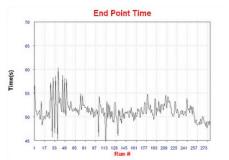


Sigma\_P : Example of Endpoint detection display



Process time (sec)



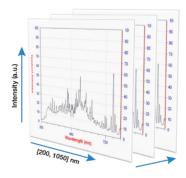


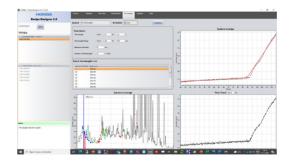
Sigma\_P: Example of statistical results

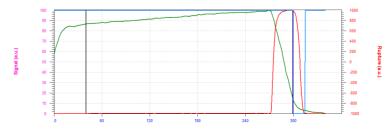
# RECIPE DESIGNER 2.0 : Engineering software for automatic endpoint recipe creation

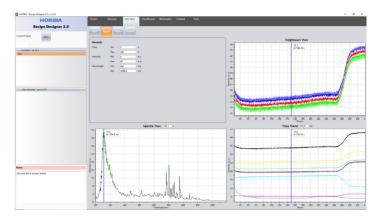
This software has been developed to allow any user, without specific skills, to build an endpoint recipe automatically. By loading a batch of representative spectra acquired with SIGMA\_P software, the software automatically identifies the best wavelengths, selecting for EPD accuracy and then creates a recipe. This recipe can be imported into the SIGMA\_P software platform to first check method robustness and then to perform real process control.

- Unique and powerful endpoint recipe creation
- Easy to use interface
- Recipe built with real acquisitions
- Automatic wavelengths selection, slope analysis and endpoint recipe creation
- Recipe robustness check on equivalent runs
- Export endpoint recipe to SIGMA\_P









RECIPE DESIGNER 2.0: Example of wavelengths/species trends evolution during process

### **Endpoint detection flow chart**



Run acquisitions (raw data) with SIGMA\_P



Automatic wavelengths selection and rupture slope conditions for endpoint calculated (RECIPE DESIGNER 2.0)



Reprocessing EPD recipe optimization and then "real time" EPD acquisitions to check method robustness (SIGMA\_P)



Start of production control: SIGMA\_P

# Different configurations of sensors and software tools

HORIBA OES sensors can be provided in different configurations:

1

**Complete Instrument:** Sensors with computer and full software package (Sigma\_P & RECIPE Designer 2.0) for easy integration and process control.

Category	Sensor and full software		
Application	Single chamber Cluster tool		
Model	EV 2.0 PC-LR or PC-STD or PC-HR or PC-HTR	EV 2000	EV 2006
Sensor Model	EV 2.0 LR or STD or HR or HTR		
Configuration	1 PC + 1 sensor	(1 PC + 1 sensor) per chamber + 1 master PC	Only 1 sensor per chamber + 1 master PC
Tools integration			
Software function			
<ul> <li>Spectra acquisition</li> </ul>	✓ by Sigma-P		
<ul> <li>Endpoint recipe management</li> </ul>	✓ by Sigma-P		
<ul> <li>Statistical analysis</li> </ul>	✓ by Sigma-P		
<ul> <li>Spectrum analysis for automatic process engineering</li> </ul>	✓ by Recipe Designer 2.0		
<ul> <li>Rupture algorithm and endpoint recipe creation</li> </ul>	✓ by Recipe Designer 2.0		





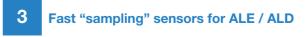
#### 2 Sensors only

• Sensors with Application Programmatic Interface (API), that includes several type of tools, which the user can use to develop to develop their own software for their specific application.

Sensors with internal smart calculation based on 1 or 2 wavelengths including various signal treatments. •

Category	Sensor, Application Programatic Interface (API)	Sensor Smart 1.0	
Application	Single chamber		
Model	EV 2.0 API LR or STD or HR or HTR	EV 2.0 Smart 1.0-LR or STD or HR or HTR	
Sensor Model	EV 2.0 LR or STD or HTR		
PC	no PC		
Configuration	Sensor + Software demonstration + SDK (Software Development Kit)	Sensor* (internal calc) + basic Recipe Editor + software guidelines	
Interface (independent from operating system)	Ethernet TCP/IP or customs (USB, ttl uart)		
Messaging	JSON		
Software Development kit provided	<ul> <li>Documentation</li> <li>Source code samples</li> <li>Demonstration software JYST PC Win*</li> <li>API Spectrometer firmware upgrade file</li> </ul>	<ul> <li>Documentation</li> <li>Source code samples</li> <li>Demonstration software JYST PC Win*</li> <li>SMART 1.0 Spectrometer firmware upgrade file</li> <li>Recipe Editor to manage Time trend recipes</li> </ul>	
Functions	<ul> <li>Basic functions available and Managed by integrators for its own application:</li> <li>Main functions on SDK: <ul> <li>Spectra acquisition (single, continuous, timed periodic, trigger)</li> <li>ROI Modes (pixel range, wavelength range, image)</li> <li>Various signal treatment</li> <li>Analog output</li> <li>General purpose I/O</li> <li>configuration (calibration)</li> </ul> </li> </ul>	Internal SMART functions immediately available in recipes  Main functions on RECIPE: Vavelength(s) acquisition (timed periodic) ROI Modes (pixel range, wavelength range) Various signal treatment Analog output General purpose I/O Sensor basic calculation (formula, filtering) Recipe management: Modify/edit/save/ download Remote control process automation: Set recipe/ Start/Stop	

\* JYST: basic software application to monitor spectra (csv format)



For specific applications with fast cycles, such as ALE or ALD, sensors with faster exposure time (down to 0.1 ms) and sampling (down to 1.4 ms) can be supplied.

# HORIBA global portfolio for semiconductor applications

# Endpoint process sensors

HORIBA has developed a full product line of sensors dedicated to real-time in-situ advanced endpoint process control, fault detection and chamber health monitoring for semiconductor industries.

Complementary to these OES sensors, based on plasma monitoring, another series of sensors, based on laser or multi wavelength interferometry, monitor wafer changes during processes.

These allow:

- Endpoint on thickness
- Etch and deposition rate and thickness measurement
- Endpoint by fringe counting
- Stop on remaining thickness





LEM Camera

EV 2.0 Spectrometer

All these sensor solutions can be used in a large range of processes such as Dry Etching, cleaning and (Plasma Enhanced) Chemical Vapor Deposition or Atomic Layer Deposition / Atomic Layer Etching.

### Research and Academic sensors

For applications, requiring wider spectral range or higher resolution, HORIBA can customize solutions based on specific customer requirements.

#### Dry process complete solutions HORIBA has a full product line of dry process sensors and also metrology equipment based on various principles to support semiconductor process control characterization needs. 101-200 Direct Injection System Ges M VC-1000 ILE S Liquid Source pact Bak Vaporization System LSC Series

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